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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT1023R

Silicon P Channel Power MOS FET High Speed Power Switching

REJ03G1145-0900

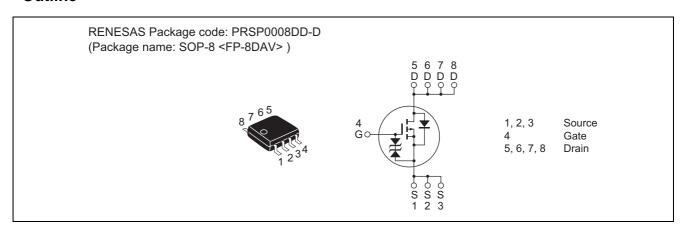
(Previous: ADE-208-436G)

Rev.9.00 Sep 07, 2005

Features

- Low on-resistance
- Capable of 2.5 V gate drive
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|--|-------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | -20 | V |
| Gate to source voltage | V _{GSS} | ±10 | V |
| Drain current | I _D | -7 | A |
| Drain peak current | I _{D (pulse)} Note 1 | -56 | A |
| Body-drain diode reverse drain current | I _{DR} | -7 | А |
| Channel dissipation | Pch Note 2 | 2.5 | W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. When using the glass epoxy board (FR4 $40\times40\times1.6$ mm), PW ≤10 s

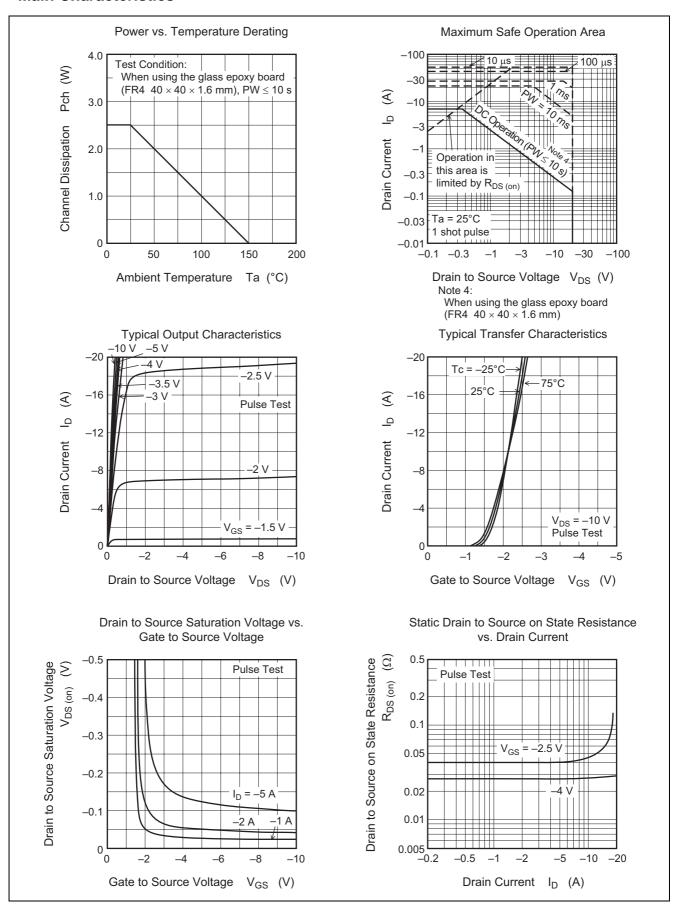
Electrical Characteristics

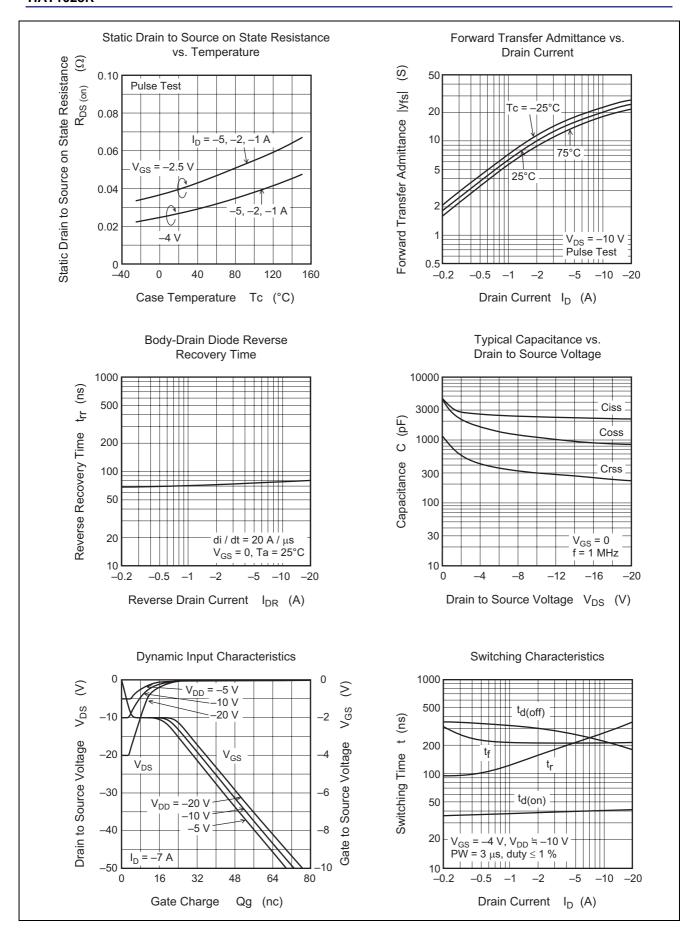
 $(Ta = 25^{\circ}C)$

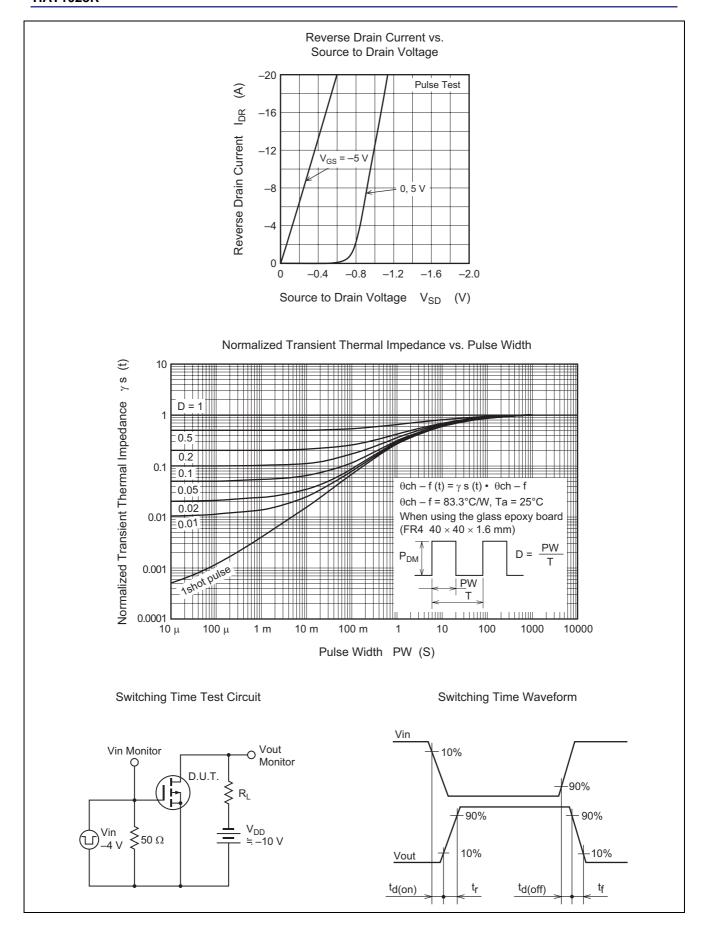
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|--|-----------------------|------|-------|------|------|---|
| Drain to source breakdown voltage | V _{(BR) DSS} | -20 | _ | _ | V | $I_D = -10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | V _{(BR) GSS} | ±10 | _ | _ | V | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | -10 | μΑ | $V_{DS} = -20 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | V _{GS (off)} | -0.5 | _ | -1.5 | V | $V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$ |
| Static drain to source on state resistance | R _{DS (on)} | _ | 0.027 | 0.04 | Ω | $I_D = -4 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 3}}$ |
| | R _{DS (on)} | _ | 0.04 | 0.06 | Ω | $I_D = -4 \text{ A}, V_{GS} = -2.5 \text{ V}^{\text{Note 3}}$ |
| Forward transfer admittance | y _{fs} | 9 | 14 | _ | S | $I_D = -4 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 3}}$ |
| Input capacitance | Ciss | _ | 2250 | _ | pF | V _{DS} = -10 V |
| Output capacitance | Coss | _ | 1120 | _ | pF | $V_{GS} = 0$ |
| Reverse transfer capacitance | Crss | _ | 300 | _ | pF | f = 1 MHz |
| Turn-on delay time | t _{d (on)} | _ | 40 | _ | ns | $V_{GS} = -4 \text{ V}, I_D = -4 \text{ A},$ |
| Rise time | t _r | _ | 200 | _ | ns | V _{DD} ≅ −10 V |
| Turn-off delay time | t _{d (off)} | _ | 280 | _ | ns | |
| Fall time | t _f | _ | 220 | _ | ns | |
| Body-drain diode forward voltage | V_{DF} | _ | -0.9 | -1.4 | V | $I_F = -7 \text{ A}, V_{GS} = 0^{\text{Note 3}}$ |
| Body-drain diode reverse recovery time | t _{rr} | _ | 75 | _ | ns | $I_F = -7 \text{ A}, V_{GS} = 0$ |
| | | | | | | $di_F/dt = 20 A/\mu s$ |

Note: 3. Pulse test

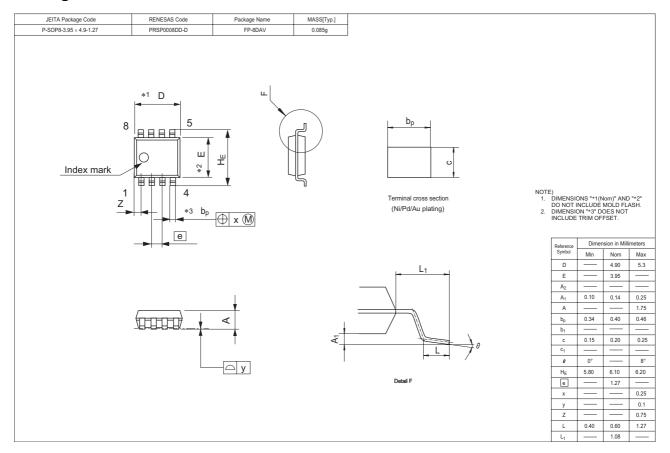
Main Characteristics







Package Dimensions



Ordering Information

| Part Name | Quantity | Shipping Container |
|---------------|----------|--------------------|
| HAT1023R-EL-E | 2500 pcs | Taping |

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